



A Product Line of Diodes Incorporated

# LITE-ON SEMICONDUCTOR

# HYPER FAST GLASS PASSIVATED RECTIFIERS

# FEATURES

- Ultrafast, soft recovery
- Very low conduction and switching losses
- · High reverse voltage capability
- Qualification is according to AEC-Q101 Rev\_C
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### APPLICATION

- Industrial power supplies, motor controls and similar mission-critical systems
- · Snubbers, bootstraps and demagnetization applications

### **MECHANICAL DATA**

- Package: JEDEC TO-220ACFP
- Package Material: "Green" molding compound, UL flammability classification 94V-0, "Halogen-free".
- Lead free finish, RoHS compliant
- Weight: 1.497 grams (Approximate)
- Marking code: LTTH812FW

# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

### **ABSOLUTE RATINGS**

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	1200	V
Maximum DC blocking voltage		V <sub>DC</sub>	1200	V
Maximum Average rectified output current	@T <sub>c</sub> =100°C	I <sub>(AV)</sub>	8	А
Peak forward surge current 10ms single half sine-wave superimposed on rated load.		I <sub>FSM</sub>	80	А
Operating junction and Storage Temperature range		T <sub>J,</sub> T <sub>STG</sub>	-55 ~ +150	°C

#### STATIC ELECTRICAL CHARACTERISTICS

STATIC ELECTRICAL CHARACTERISTICS							
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP	MAX	UNIT	
Forward voltage (Note 4)	I <sub>F</sub> =8A	T <sub>J</sub> =25°C T <sub>J</sub> =125°C	VF	 1.4	2.2 2.0	V	
Leakage current	V <sub>R</sub> =1200V	T」=25°C T」=125°C	I <sub>R</sub>	 25.6	8 50	uA	
Typical junction capacitance (Note 5)		CJ	48		pF		

# DYNAMIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITIONS		SYMBOL	TYP	MAX	UNIT
	I <sub>F</sub> =0.5A, I <sub>rr</sub> =0.25A, I <sub>R</sub> =1.0A			61	100	
Reverse recovery charges	$I_F=1A$ , dl/dt= 50A/uS, $V_R=30V$ ,	TJ=25°C	T <sub>rr</sub>	78	100	nS
	I <sub>F</sub> =1A,dI/dt= 100A/uS, V <sub>R</sub> =30V			46	70	1
Reverse recovery current	I <sub>F</sub> =8A , dl/dt=200A/uS,V <sub>R</sub> =400V,	TJ=125°C	I <sub>RM</sub>	14	21	А

THERMAL CHARACTERISTICS	
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PARAMETER	SYMBOL	ТҮР	UNIT
Typical thermal resistance (Note 6.7)	RthJ <sub>c</sub>	3	°C/W
Typical thermal resistance (Note 6,7)	RthJ∟	4	C/W

Note:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/guality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm

antimony compounds.

4. 300us pulse width, 2% duty cycle.

5. Measured at 1.0MHz and applied voltage of 4.0V DC.

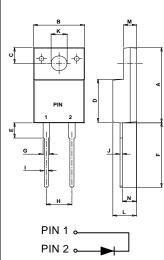
6. Thermal resistance test performed in accordance with JESD-51.

7. The unit mounted on Aluminum heat sink (100mm x 100mm x 1.9mm).

REVERSE VOLTAGE FORWARD CURRENT

– 1200 Volts– 8 Amperes

### ITO-220AC(WB)



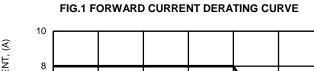
IT	ITO-220AC(WB)					
DIM	/ MIN MAX					
Α	15.33	15.62				
В	10.00	10.40				
С	2.91	3.21				
D	8.50	8.80				
E	3.30	3.90				
F	13.00	13.70				
G	1.15	1.70				
Н	4.95	5.25				
1	0.50	0.80				
J	0.45	0.70				
K	3.00 Ø	3.30 Ø				
L	4.46	4.87				
М	2.48	2.80				
Ν	2.50	2.80				
All dimension in millimeter						



# RATING AND CHARACTERISTIC CURVES LTTH812FW

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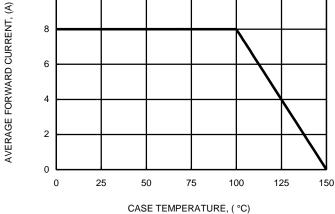


FIG.2 MAXIMUM NON-REPETITIVE SURGE CURRENT

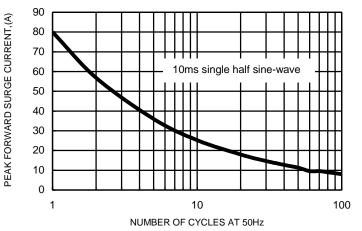
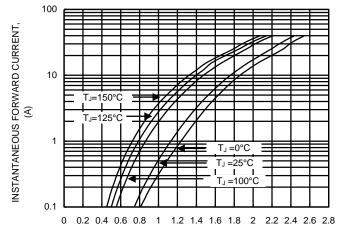


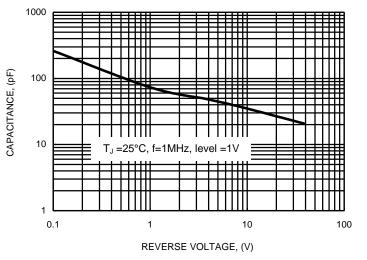
FIG.3 TYPICAL FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE, (V)

FIG.5 TYPICAL REVERSE CHARACTERISTICS 100 T<sub>J</sub> =150°C T<sub>J</sub> =125°C **NSTANTANEOUS REVERSE CURRENT**, 10 T<sub>J</sub> =100°C 1 (M) 0.1 T<sub>J</sub>=25°C 0.01 T<sub>J</sub> =0°C 0.001 0 240 480 720 960 1200 1440 RATED PEAK REVERSE VOLTAGE, (V)

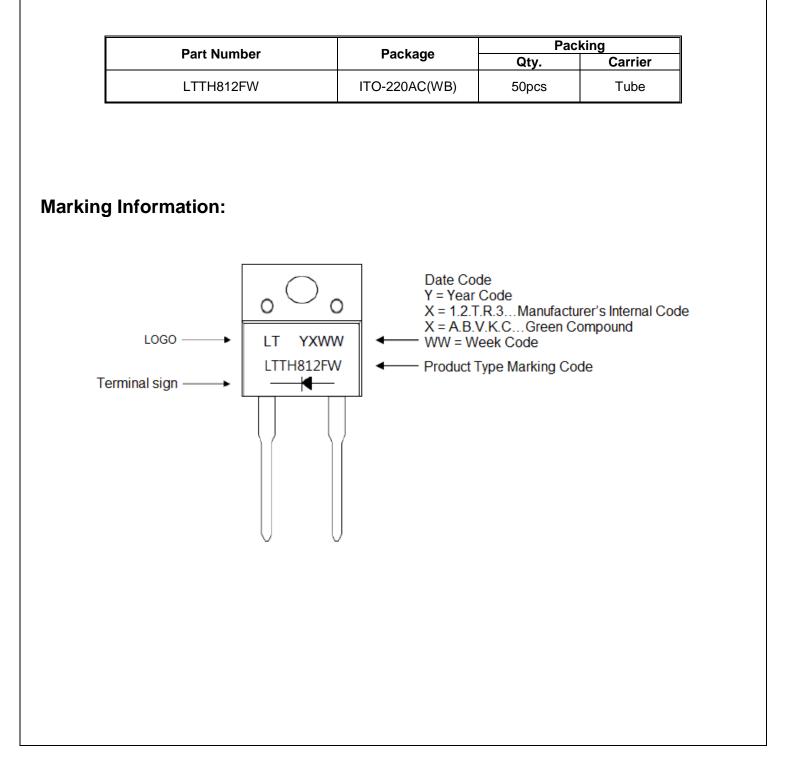
FIG.4 TYPICAL JUNCTION CAPACITANCE





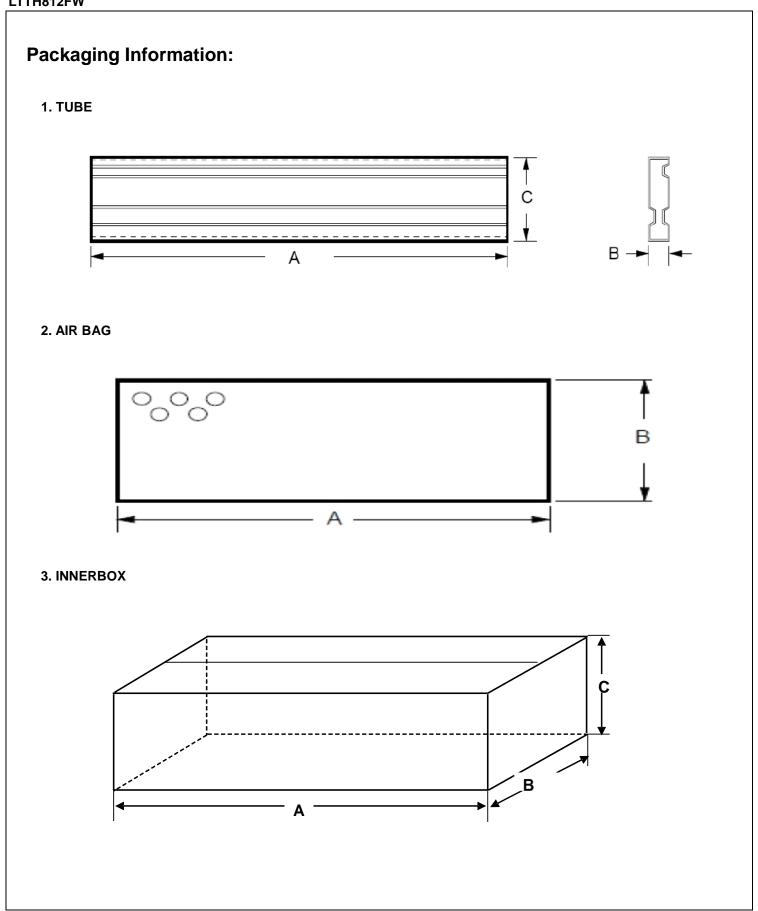
# LITE-ON SEMICONDUCTOR

# Ordering Information:





# LITE-ON SEMICONDUCTOR

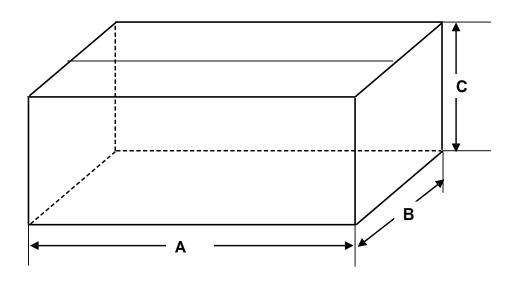




# LITE-ON SEMICONDUCTOR

# Packaging Information: (continued)

# 4. CARTON



### Unit: mm

P/N	DIMENSION "A"	DIMENSION "B"	DIMENSION "C"	Q'ty/per	REMARK
TUBE	536	5.6	31.8	50	1
AIR BAG	800	550	1	1	1
INNERBOX	555	165	105	2000	40TUBE
CARTON	575	179	225	4K	2 INNER BOX





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